

# SI3459DV-T1-E3

uest a Quote

## SI3459DV-T1-E3 Information

| www.bakener.com    | Part Number  | SI3459DV-T1-E3  |   |
|--------------------|--------------|---|---|
|                    | Manufacturer | Vishay Siliconix  | Г |
|                    | Category     | Discrete Semiconductor Products<br>Transistors - FETs, MOSFETs - Single | ļ |
|                    | Description  | MOSFET P-CH 60V 2.2A 6-TSOP   | Ż |
|                    | Package      | SOT-23-6 Thin, TSOT-23-6  | ī |
|                    |              | For the pricing/inventory/lead time, please contact                     | L |
|                    |              | us  |   |
| For Reference Only |              | Website: https://www.heisener.com<br>E-mail: salesdept@heisener.com     | I |

## **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



## SI3459DV-T1-E3 Specifications

| Manufacturer Part Number               | SI3459DV-T1-E3                       |
|--|--------------------------------------|
| Manufacturer                           | Vishay Siliconix                     |
| Category                               | Discrete Semiconductor Products      |
|  | Transistors - FETs, MOSFETs - Single |
| Package                                | SOT-23-6 Thin, TSOT-23-6             |
| Series                                 | TrenchFET?                           |
| FET Type                               | P-Channel                            |
| Technology                             | MOSFET (Metal Oxide)                 |
| Drain to Source Voltage (Vdss)         | 60V                                  |
| Current - Continuous Drain (Id) @ 25°C | 2.2A (Tc)                            |
| Drive Voltage (Max Rds On, Min Rds On) | 4.5V, 10V                            |
| Vgs(th) (Max) @ Id                     | 1V @ 250µA (Min)                     |
| Gate Charge (Qg) (Max) @ Vgs           | 14nC @ 10V                           |
| Input Capacitance (Ciss) (Max) @ Vds   | -                                    |
| Vgs (Max)                              | $\pm 20 V$                           |
| FET Feature                            | -                                    |
| Power Dissipation (Max)                | 2W (Ta)                              |
| Rds On (Max) @ Id, Vgs                 | 220 mOhm @ 2.2A, 10V                 |
| Operating Temperature                  | -55°C ~ 150°C (TJ)                   |
| Mounting Type                          | Surface Mount                        |
| Supplier Device Package                | 6-TSOP                               |
| Package / Case                         | SOT-23-6 Thin, TSOT-23-6             |
|  | Report errors?                       |

#### SI3459DV-T1-E3 Guarantees



Quality Guarantees

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

### SI3459DV-T1-E3 Payment Methods



## SI3459DV-T1-E3 Shipping Methods



If you have any question about SI3459DV-T1-E3, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com